

LISTING OF CLAIMS

The following listing of claims will replace all prior versions, and listings, of claims in the application.

- 5 1. (Currently Amended) A sense amplifier, comprising:
an input stage having a pair of balanced isolation devices, each of the pair of balanced isolation devices having an input connected to receive a separate one of a pair of differential input signals, each of the pair of balanced isolation devices having a gate connected to receive a common bias voltage; and
10 a sense stage having a pair of sense nodes connected to the input stage, the sense stage being configured to receive respective output signals from the pair of balanced isolation devices of the input stage, the sense stage being further configured to and amplify a voltage of the received output signal having the higher voltage a higher signal to be provided by the pair of balanced isolation devices of the input stage, wherein the
15 sense stage includes a pair of booster circuits, each of the pair of booster circuits being configured to assist in a low-to-high state transition of a separate one of the pair of sense nodes during a sensing operation.

2. (Original) A sense amplifier as recited in claim 1, wherein the gates of
20 the pair of balanced isolation devices are connected together to receive the common bias voltage.

3. (Original) A sense amplifier as recited in claim 1, wherein each of the pair of balanced isolation devices is defined as a PMOS device.

4. (Original) A sense amplifier as recited in claim 1, wherein the common bias voltage is provided by a bias generator circuit.

5. (Original) A sense amplifier as recited in claim 1, wherein the common bias voltage is maintained at a level that is about one-half of a supply voltage level.

6. (Currently Amended) A sense amplifier as recited in claim 1, wherein ~~the sense stage includes a pair of sense nodes~~, each of the pair of sense nodes is being connected to an output of a separate one of the pair of balanced isolation devices of the input stage.

7. (Currently Amended) A sense amplifier as recited in claim 1 [[6]], wherein the sense stage includes a transmission gate disposed between the pair of sense nodes, the transmission gate being configured to control electrical conduction between the pair of sense nodes, the transmission gate being further configured to operate in response to an equalization control signal.

8. (Currently Amended) A sense amplifier as recited in claim 1 [[6]], wherein ~~the sense stage includes a pair of booster circuits, each of the pair of booster circuits being configured to assist in a low to high state transition of a separate one of the pair of sense nodes, each of the pair of booster circuits being further configured to operate in response to an equalization control signal~~ each of the pair of booster circuits includes, a NAND device connected to receive an equalization control signal as a first input and a state of the sense node to which the booster circuit is connected as a second input,

a PMOS device having an input connected to a supply voltage and an output connected to the sense node to which the booster circuit is connected, the PMOS device having a gate connected to receive an output of the NAND device.

- 5 9. (Currently Amended) A sense amplifier, comprising:
- a pair of input nodes connected to each receive a separate one of a pair of differential input signals;
- a pair of balanced isolation devices each having an input connected to a separate one of the pair of input nodes, the pair of balanced isolation devices each having a gate connected to receive a common bias voltage, the pair of balanced isolation devices each having an output representing a separate one of a pair of sense nodes;
- a transmission gate disposed between the pair of sense nodes, the transmission gate being configured to control conduction between the pair of sense nodes; and
- pull down logic being connected to the pair of sense nodes; and
- 10 15 a pair of booster devices configured to assist a low-to-high state transition of a respective one of the pair of sense nodes during a sensing operation.
10. (Original) A sense amplifier as recited in claim 9, wherein each of the pair of balanced isolation devices is a PMOS device.
- 20 11. (Original) A sense amplifier as recited in claim 9, wherein the transmission gate includes a PMOS device having a first terminal connected to one of the pair of sense nodes and a second terminal connected to the other of the pair of sense nodes, the transmission gate PMOS device having a gate connected to receive an equalization control signal.

12. (Cancelled)

13. (Currently Amended) A sense amplifier as recited in claim 9 [[+2]],
5 wherein each of the pair of booster devices includes,

a NAND device connected to receive an equalization control signal as a first input
and a state of the sense node to which the booster device is connected as a second input,
a PMOS device having an input connected to a supply voltage and an output
connected to the sense node to which the booster device is connected, the PMOS device
10 having a gate connected to receive an output of the NAND device,

wherein receipt of a low equalization control signal causes the output of the
NAND device to maintain a high state such that the PMOS device is controlled to not
transmit, receipt of a high equalization control signal causing the output of the NAND
device to attain a state opposite from a state of the sense node to which the booster device
15 is connected.

14. (Currently Amended) A sense amplifier as recited in claim 9, further
comprising:

a pair of charging devices each being configured to supply a steady voltage to a
20 separate one of the pair of input nodes upon receipt of a recovery activation signal.

15. (Original) A sense amplifier as recited in claim 14, wherein each of
the pair of charging devices is a PMOS device having an output connected to one of the
pair of input nodes, an input connected to a supply voltage, and a gate connected to
25 ground.

16. (Original) A sense amplifier as recited in claim 9, further comprising:
a bias generator configured to supply the common bias voltage to the gates of the pair of balanced isolation devices.

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17. (Original) A sense amplifier as recited in claim 16, wherein the bias generator is configured to maintain the common bias voltage at about one-half of a supply voltage level.

10 18. (Original) A sense amplifier as recited in claim 9, further comprising:
a recovery stage configured to assist charging and equalizing the pair of input nodes prior to activating the sense amplifier to perform a sensing operation.

15 19. (Original) A sense amplifier as recited in claim 9, wherein the pull down logic includes a pair of NMOS devices each having an input connected to a separate one of the pair of sense nodes, each of the pair of NMOS devices having a gate connected to the input of the other one of the pair of NMOS devices, each of the pair of NMOS devices having an output connected to ground.

20 20. (Currently Amended) A method for making a sense amplifier, comprising:
connecting a pair of input nodes to each receive a separate one of a pair of differential input signals;
connecting an input of each of a pair of balanced isolation devices to a separate one of the pair of input nodes, wherein each of the pair of balanced isolation devices has
25 an output representing a separate one of a pair of sense nodes;

connecting a gate of each of the pair of balanced isolation devices to receive a common bias voltage;

connecting each of a first terminal and a second terminal of a transmission gate to a separate one of the pair of sense nodes; and

5 connecting pull down circuitry to the pair of sense nodes; and

connecting each of a pair of booster devices to a separate one of the pair of sense nodes, each of the pair of booster devices being configured to assist a low-to-high state transition of the sense node to which the booster device is connected during a sensing operation.

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21. (Original) A method for making a sense amplifier as recited in claim 20, wherein each of the pair of balanced isolation devices is defined as a PMOS device.

15 22. (Original) A method for making a sense amplifier as recited in claim 20, wherein the transmission gate is defined as a PMOS device.

23. (Original) A method for making a sense amplifier as recited in claim 22, further comprising:

20 connecting a gate of the PMOS device of the transmission gate to receive an equalization control signal.

24. (Cancelled)

25. (Currently Amended) A method for making a sense amplifier as recited in claim 20 [[24]], wherein connecting each of the pair of booster devices to the separate one of the pair of sense nodes includes,

connecting a first input of a NAND device to receive an equalization control
5 signal,

connecting a second input of the NAND device to receive a state of the sense node to which the booster device is connected,

connecting an input of a PMOS device to a supply voltage,

10 connecting an output of the PMOS device to the sense node to which the booster device is connected, and

connecting a gate of the PMOS device to receive an output of the NAND device.

26. (Currently Amended) A method for making a sense amplifier as recited in claim 20, further comprising:

15 connecting an output of each of a ~~second~~ pair of PMOS devices to a separate one of the pair of input nodes;

connecting an input of each of the ~~second~~ pair of PMOS devices to a supply voltage; and

connecting a gate of each of the ~~second~~ pair of PMOS devices to a ground.

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27. (Original) A method for making a sense amplifier as recited in claim 20, further comprising:

connecting a bias generator to supply the common bias voltage to the gates of the pair of balanced isolation devices, wherein the bias generator is defined to maintain the
25 common bias voltage at about one-half of a supply voltage level.

28. (Original) A method for making a sense amplifier as recited in claim 20, further comprising:

connecting a recovery stage to the pair of input nodes, wherein the recovery stage 5 is defined to assist in charging and equalizing the pair of input nodes prior to activating the sense amplifier to perform a sensing operation.

29. (Original) A method for making a sense amplifier as recited in claim 20, wherein connecting pull down circuitry to the pair of sense nodes includes,

10 connecting an input of each of a pair of NMOS devices to a separate one of the pair of sense nodes,

connecting an output of each of the pair of NMOS devices to a ground, and

connecting a gate of each of the pair of NMOS devices to the input of the other one of the pair of NMOS devices.

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